MPS651 and MPS751 are Preferred Devices

Amplifier Transistors

Features

• Pb-Free Packages are Available*

MAXIMUM RATINGS

Rating	Symbol	MPS650 MPS750	MPS651 MPS751	Unit
Collector - Emitter Voltage	V _{CE}	40	60	Vdc
Collector - Base Voltage	V _{CB}	60 80		Vdc
Emitter – Base Voltage	V _{EB}	5.0		Vdc
Collector Current – Continuous	Ι _C	2.0		Adc
Total Power Dissipation @ T _A = 25°C Derate above 25°C	P _D	625 5.0		mW mW/°C
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	1.5 12		W mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150		°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

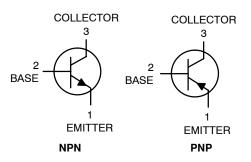
Characteristic	Symbol	Мах	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

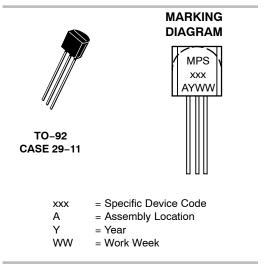
*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



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ORDERING INFORMATION

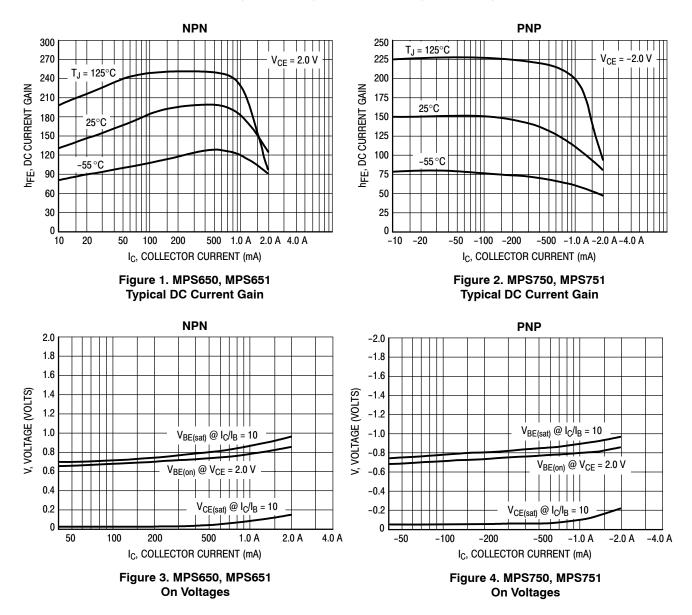
See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

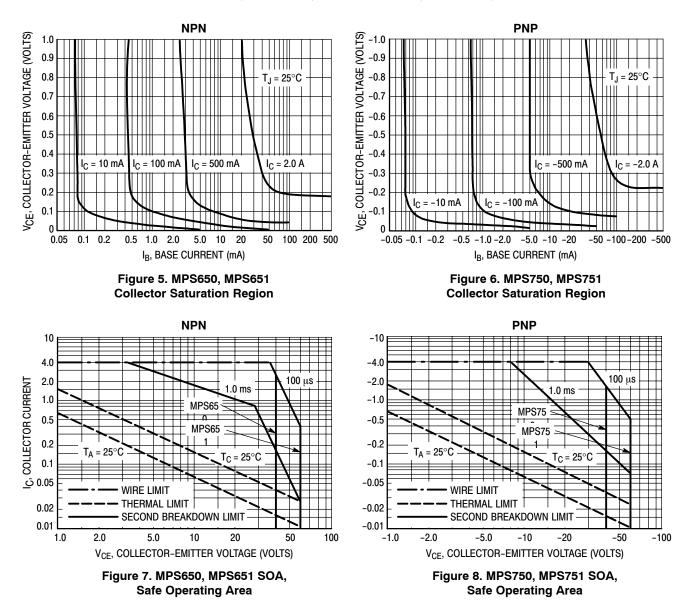
Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					•
Collector – Emitter Breakdown Voltage (Note $(I_C = 10 \text{ mAdc}, I_B = 0)$	1) MPS650, MPS750 MPS651, MPS751	V _{(BR)CEO}	40 60		Vdc
Collector – Base Breakdown Voltage ($I_C = 100 \ \mu Adc, I_E = 0$)	MPS650, MPS750 MPS651, MPS751	V _{(BR)CBO}	60 80		Vdc
Emitter – Base Breakdown Voltage ($I_C = 0, I_E = 10 \ \mu Adc$)		V _{(BR)EBO}	5.0	-	Vdc
Collector Cutoff Current ($V_{CB} = 60 \text{ Vdc}, I_E = 0$) ($V_{CB} = 80 \text{ Vdc}, I_E = 0$)	MPS650, MPS750 MPS651, MPS751	I _{CBO}	-	0.1 0.1	μAdc
Emitter Cutoff Current ($V_{EB} = 4.0 \text{ V}, I_C = 0$)		I _{EBO}	-	0.1	μAdc
ON CHARACTERISTICS (Note 1)					1
$ \begin{array}{l} \text{DC Current Gain} \\ (I_{C} = 50 \text{ mA}, \text{ V}_{CE} = 2.0 \text{ V}) \\ (I_{C} = 500 \text{ mA}, \text{ V}_{CE} = 2.0 \text{ V}) \\ (I_{C} = 1.0 \text{ A}, \text{ V}_{CE} = 2.0 \text{ V}) \\ (I_{C} = 2.0 \text{ A}, \text{ V}_{CE} = 2.0 \text{ V}) \end{array} $		h _{FE}	75 75 75 40		_
$\label{eq:local_constraint} \begin{array}{l} \mbox{Collector}-\mbox{Emitter Saturation Voltage} \\ (I_C=2.0 \mbox{ A}, \mbox{ I}_B=200 \mbox{ mA}) \\ (I_C=1.0 \mbox{ A}, \mbox{ I}_B=100 \mbox{ mA}) \end{array}$		V _{CE(sat)}	-	0.5 0.3	Vdc
Base-Emitter On Voltage (I _C = 1.0 A, V_{CE} = 2.0 V)		V _{BE(on)}	-	1.0	Vdc
Base – Emitter Saturation Voltage (I_C = 1.0 A, I_B = 100 mA)		V _{BE(sat)}	-	1.2	Vdc
SMALL-SIGNAL CHARACTERISTICS		· · ·			
Current – Gain – Bandwidth Product (Note 2 (I_C = 50 mAdc, V_{CE} = 5.0 Vdc, f = 100 MHz)		f _T	75	-	MHz

1. Pulse Test: Pulse Width \leq 300 μs , Duty Cycle = 2.0%. 2. f_T is defined as the frequency at which |h_{fe}| extrapolates to unity.





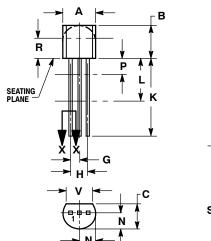
ORDERING INFORMATION

Device	vice Package Shipping [†]		
MPS650	TO-92	5000 Units / Bulk	
MPS650G	TO-92 (Pb-Free)	5000 Units / Bulk	
MPS650RLRA	TO-92	2000 / Tape & Reel	
MPS650RLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel	
MPS650ZL1	TO-92	2000 / Tape & Ammunition	
MPS650ZL1G	TO-92 (Pb-Free)	2000 / Tape & Ammunition	
MPS651	TO-92	5000 Units / Bulk	
MPS651G	TO-92 (Pb-Free)	5000 Units / Bulk	
MPS651RLRA	TO-92	2000 / Tape & Reel	
MPS651RLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel	
MPS651RLRBG	TO-92 (Pb-Free)	2000 / Tape & Reel	
MPS651RLRM	TO-92	2000 / Tape & Ammunition	
MPS651RLRMG	TO-92 (Pb-Free)	2000 / Tape & Ammunition	
MPS750	TO-92	5000 Units / Bulk	
MPS750G	TO-92 (Pb-Free)	5000 Units / Bulk	
MPS750RLRA	TO-92	2000 / Tape & Reel	
MPS750RLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel	
MPS750RLRP	TO-92	2000 / Tape & Ammunition	
MPS750RLRPG	TO-92 (Pb-Free)	2000 / Tape & Ammunition	
MPS751	TO-92	5000 Units / Bulk	
MPS751G	TO-92 (Pb-Free)	5000 Units / Bulk	
MPS751RLRA	TO-92	2000 / Tape & Reel	
MPS751RLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel	
MPS751RLRP	TO-92	2000 / Tape & Ammunition	
MPS751RLRPG	TO-92 (Pb-Free)	2000 / Tape & Ammunition	
MPS751ZL1	TO-92	2000 / Tape & Ammunition	
MPS751ZL1G	TO-92 (Pb-Free)	2000 / Tape & Ammunition	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 **ISSUE AL**





NOTES:

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

CONTROLLING DIMENSION: INCH. CONTOUR OF PACKAGE BEYOND DIMENSION R 3.

IS UNCONTROLLED. LEAD DIMENSION IS UNCONTROLLED IN P AND 4. BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Ρ		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	

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